

**MAINTENANCE MANUAL
IF/AUDIO & SQUELCH BOARD
19D417707G1 & G2**

LB14986E
(DF1105)
(DF1119)
IMTS)

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DESCRIPTION

The IF/Audio and Squelch board (IFAS) provides 120 dB IF gain, detects audio and provides squelch control. The IFAS board operates with an IF frequency of 11.2 or 9.4 MHz depending on the operating frequency of the radio. IFAS board 19D417707G1 operates with an IF frequency of 11.2 MHz and is used in radios operating in the following frequency bands:

- 25 - 30 MHz
- 36 - 42 MHz
- 66 - 88 MHz
- 138 - 174 MHz
- 406 - 420 MHz
- 450 - 512 MHz

IFAS board 19D417707G2 operates with an IF frequency of 9.4 MHz and is used in radios operating in the 30-36 MHz, 42-50 MHz, and 806-825 MHz frequency bands.

CIRCUIT ANALYSIS

Crystal Filters, IF Amp & Limiter

The IF input from the MIF or IF Filter board is applied to a four-pole monolithic crystal filter (FL601 and FL602). The crystal filter provides additional selectivity and is followed by impedance matching network Z601 and IF Amplifier IC U601. The IC amplifier provides approximately 60 dB of gain.

Final IF selectivity is provided by a two-pole crystal filter FL603. Impedance matching network Z602 matches the output impedance of IF amplifier IC U601 to the input of two-pole crystal filter FL603.

The IF amplifier output is metered at J601 through a metering network consisting of C611, C612, CR601 and CR602. Impedance matching network Z603 matches the output impedance of FL603 to the input of Limiter/Detector IC U602.

In addition to providing 60 dB of gain at the IF frequency, Limiter/Detector IC U602, C619, C620 and L603 comprise a quadrature phase detector to recover the audio from the IF frequency. The quadrature phase detector utilizes a 90 degree phase shift in the IF frequency to detect the audio signal. It compares the phase of the IF input at U602-4 with the same IF input frequency shifted 90 degrees at U602-2. The resultant signal varies phase linearly as the carrier signal deviates about the center frequency.

The detector output is adjusted for maximum audio output by L603 and is metered at J601 through R607.

AUDIO PREAMPLIFIER

The audio preamplifier consists of transistors Q601, Q602, and Q605. It provides approximately 26 dB of gain.

The output of the Limiter/Detector is coupled to the audio preamplifier through audio level adjust control R608. R608 sets the audio input level to the preamplifier circuit.

The output of the audio preamplifier is coupled through a low pass filter (L604 and C624) to volume and squelch control high. The filter removes any IF signal remaining in the audio output of the preamplifier.

AUDIO IC

The hybrid audio IC (U604) uses a custom flip-chip monolithic integrated circuit. The audio IC contains a standard EIA Channel Guard tone reject filter, a receiver de-emphasis circuit, and the low level audio PA drive circuitry.

Audio from the preamplifier is coupled through the VOLUME control to pin 4 of the audio IC from P904-13 (VOL ARM). Audio at pin 4 is applied to the Channel Guard tone reject circuit, and then to the 6 dB/octave de-emphasis circuit. The filter output is coupled through C635 to the differential audio driver circuit. The output of the audio driver circuit is DC-coupled to the push-pull, Class AB audio PA transistors, Q603 and Q604. The PA output is coupled through audio transformer T601 rated power to the 8-ohm loudspeaker. R619 and C637 in the transformer secondary protects the PA transistors against a "no-load" or open circuit. Feedback from windings T601-3 and -4 determines the gain of the audio driver amplifier.

When the receiver is squelched, pin 1 of audio IC U604 is near A-, and the entire audio circuit is turned off to eliminate current drain. Pin 1 is also connected to the system board through P904-7 (RX MUTE) so that the receiver audio can be disabled by the time delay circuit in the 10-Volt regulator, and by the Channel Guard option when used.

Pins 6 and 7 are connected to the system board through P904-16 (RX PA) and P904-21 (INTCM INPUT) so that the receiver audio stages can be used to provide an audio output when the radio is equipped with the Intercom option.

Pin 2 is connected to the system board through P904-6 (SQ DISABLE) so that the receiver audio stages can be independently activated and used to provide an alert tone output when the radio is equipped with the Carrier Controlled Timer option.

SQUELCH IC

The hybrid squelch IC (U603) also uses a custom flip-chip monolithic integrated circuit. The squelch IC contains the noise amplifier, active noise filter, detector, slow and fast squelch circuits as well as the receiver unsquelched sensor (RUS) switch, and carrier activity sensor (CAS) switch.

Noise Amp, Filter & Active Detector

Noise from the limiter/detector is coupled through the SQUELCH control to pins 1 and 2 on the squelch IC. This signal is applied to the noise amplifier and then to the active filter circuit.

The noise amp and active filter provide the gain and selectivity to distinguish between noise and audio. The filter output drives the active detector circuit to provide the squelch switching functions. Thermistor RT601 keeps the input to the active detector constant over wide variations in temperature.

Slow & Fast Squelch

With a signal below the 20 dB quieting level, the slow squelch circuit provides a conventional slow (200 millisecond) squelch operation to prevent rapid squelch opening and closing in weak signal areas.

A signal at or above the 20 dB quieting level is sensed by the signal level detector and activates the fast squelch circuit, providing a fast (10 millisecond) squelch operation.

The squelch circuits have two outputs. One output controls the squelch switch and the other output controls the CAS switch.

Squelch Switch

The squelch switch output at pin 7 is connected to pin 1 of the audio IC. When the receiver is squelched, the output pin at 7 is near A-. This keeps the receiver audio stages turned off, muting the receiver. When the receiver is quieted by an on-frequency signal (unsquelches), the voltage at pin 7 rises to approximately +10 Volts. This turns on the audio stages and sound is heard at the speaker.

With the receiver unsquelched, the output of the squelch switch turns on the RUS switch. The output of the RUS switch is connected to the noise amplifier, providing a hysteresis loop in the squelch circuit. The RUS output increases the gain of the noise amplifier, preventing squelch closing on weak signals. The RUS output at pin 8 is also connected to the system board through P904-8 for special applications.

NOTE

In radios equipped with Channel Guard, the RUS switch will operate only when an "on-frequency" signal with the correct Channel Guard tone is applied to the receiver.

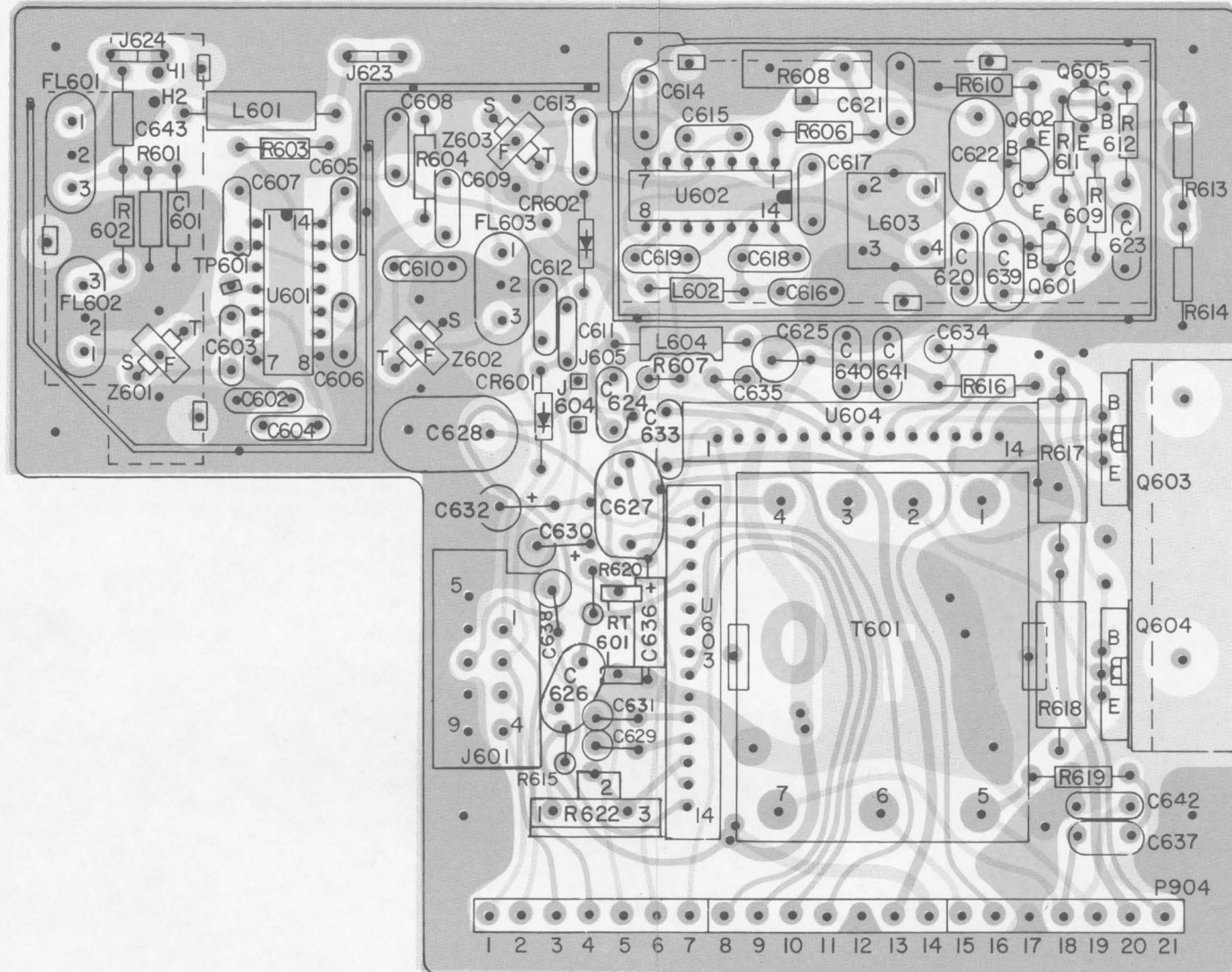
CAS Switch

The squelch circuits also drive the CAS switch. When the receiver unsquelches, the voltage at pin 6 rises to approximately 10 volts. This voltage is connected to the system board through P904-9, and is used to turn on an optional Channel Busy light on the control unit.

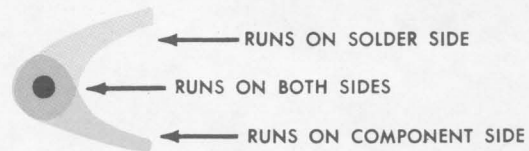
NOTE

The CAS switch will operate whenever an "on-frequency" signal is received, with or without a correct Channel Guard tone.

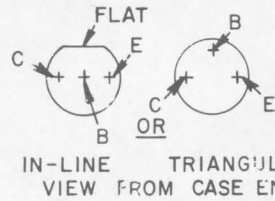
COMPONENT SIDE



(19D423789, Sh. 2, Rev. 1)
(19D423789, Sh. 3, Rev. 0)

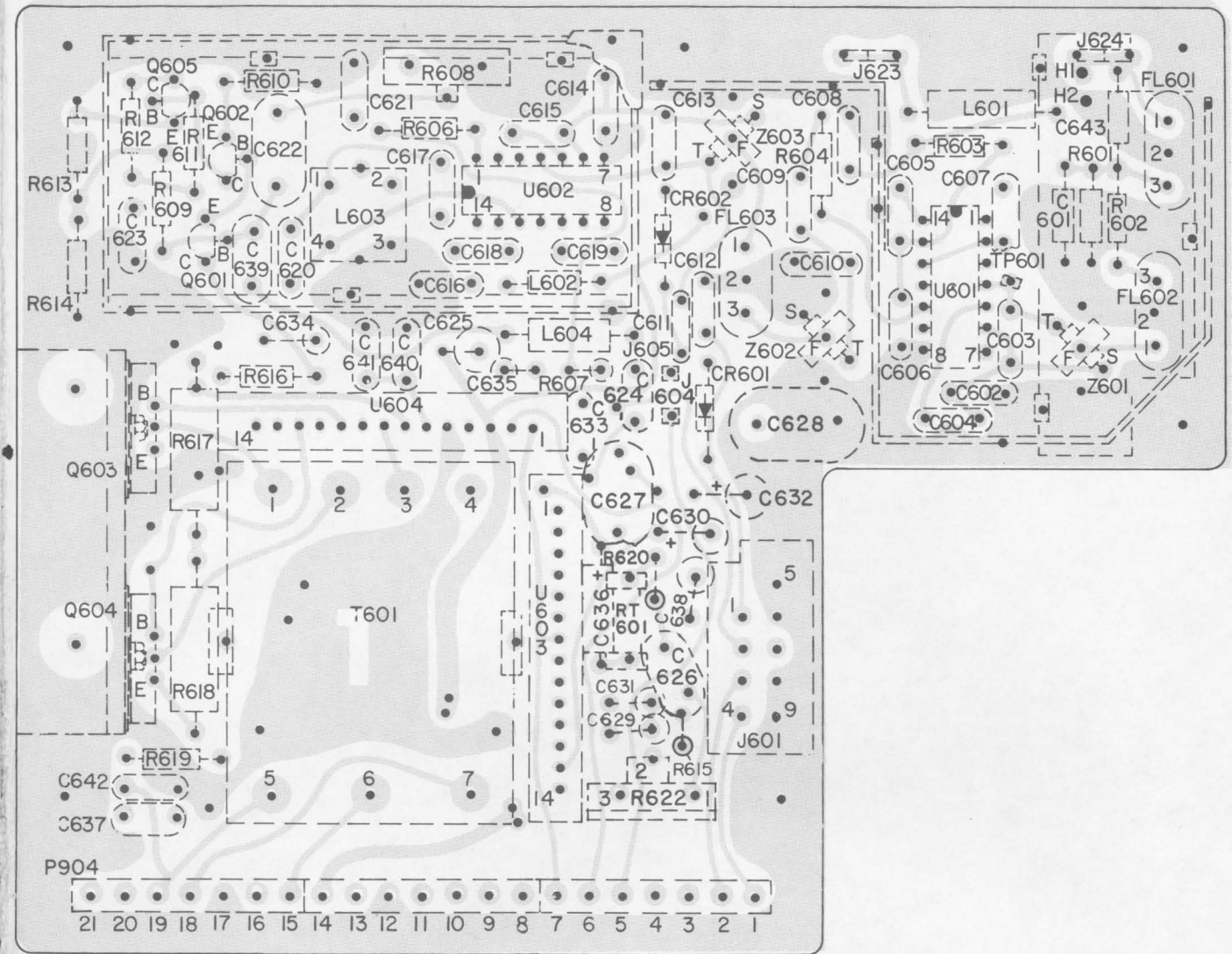


LEAD IDENTIFICATION
FOR Q601, Q602 & Q605

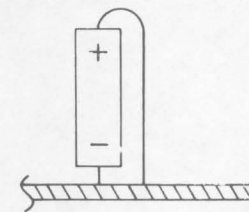


NOTE: LEAD ARRANGEMENT AND NOT CASE SHAPE IS DETERMINING FACTOR FOR LEAD IDENTIFICATION. TAB INDICATES EMITTER LEAD.

SOLDER SIDE



(19D423789, Sh. 2, Rev. 1)

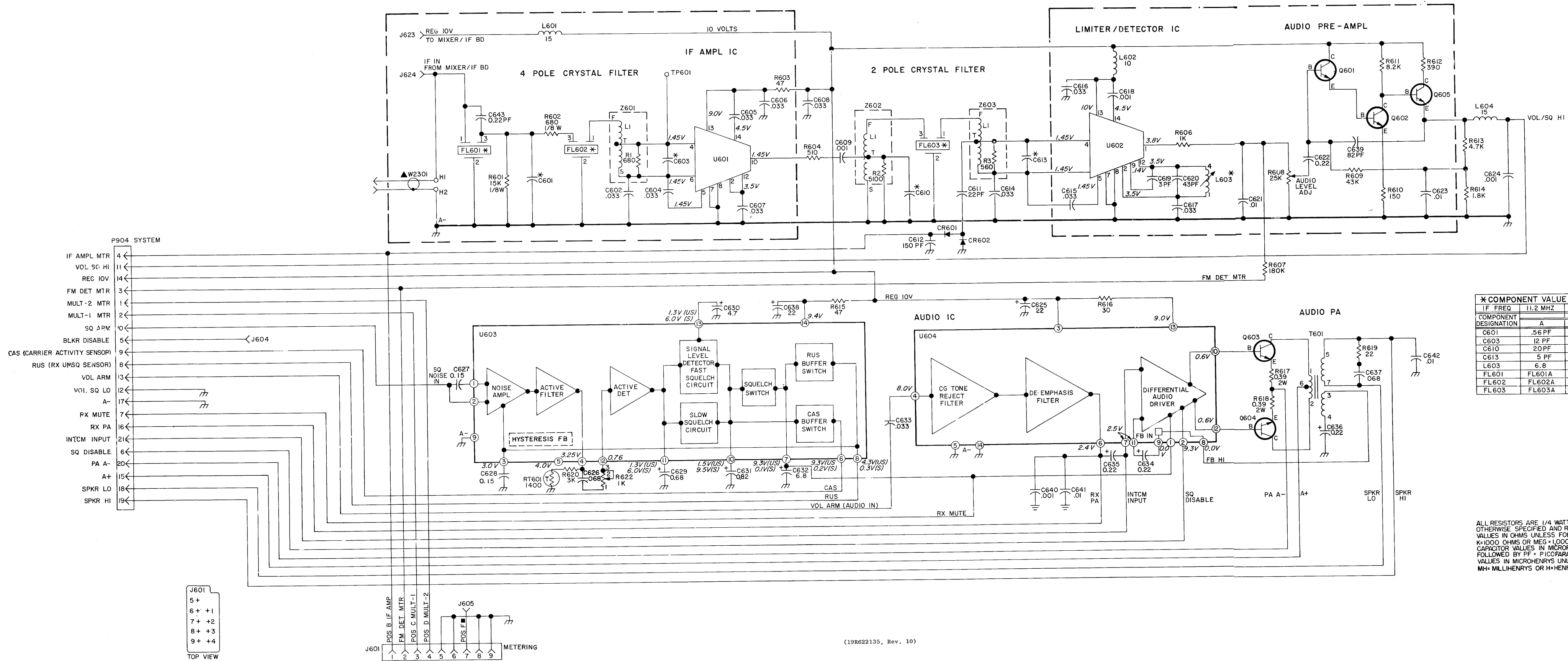


POLARITY FOR
C634, C635, C630,
C632, C625, C638,
C631 & C629

(19D423600, Rev. 2)

OUTLINE DIAGRAM

IF/AUDIO/SQUELCH BOARD
19D417707G1 & G2



(19R622135, Rev. 10)

SCHEMATIC DIAGRAM
 IF/AUDIO/SQUELCH BOARD
 19D417707G1 & G2

PARTS LIST

LBI4987D
 IF/AUDIO/SQUELCH BOARD
 19D417707G1 11.2 MHz IF/AUDIO SQUELCH (A)
 19D417707G2 9.4 MHz IF/AUDIO SQUELCH (B)

SYMBOL	GE PART NO.	DESCRIPTION
----- CAPACITORS -----		
C601A	5491801P115	Phenolic: 0.56 pf ±5%, 500 VDCW.
C601B	5491801P123	Phenolic: 1.5 pf ±5%, 500 VDCW.
C602	19A116080P104	Polyester: 0.033 µf ±10%, 50 VDCW.
C603A	5496219P642	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -470 PPM.
C603B*	5496219P638	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp coef -470 PPM. In REV E and earlier:
	5496219P647	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -470 PPM.
C604 thru C608	19A116080P104	Polyester: 0.033 µf ±10%, 50 VDCW.
C609	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C610A	5496219P646	Ceramic disc: 20 pf ±5%, 500 VDCW, temp coef -470 PPM.
C610B*	5496219P644	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -470 PPM. In REV E and earlier:
	5496219P649	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -470 PPM.
C611	5496219P647	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -470 PPM.
C612	5494481P101	Ceramic disc: 150 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C613A*	5496219P636	Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp coef -470 PPM. In REV B-D:
	5496219P642	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -470 PPM.
	5496219P636	Ceramic disc: 5.0 pf ±0.25 pf, 500 VDCW, temp coef -470 PPM. In REV A and earlier:
C613B*	5496219P645	Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef -470 PPM. In REV E:
	5496219P649	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef -470 PPM. In REV D and earlier:
	5496219P645	Ceramic disc: 18 pf ±5%, 500 VDCW, temp coef -470 PPM.
C614 thru C617	19A116080P104	Polyester: 0.033 µf ±10%, 50 VDCW.
C618	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C619	19A116656P3J1	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef -150 PPM.
C620	19A116656P43J1	Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef -150 PPM.
C621	19A116080P101	Polyester: 0.01 µf ±10%, 50 VDCW.
C622	19A116080P109	Polyester: 0.22 µf ±10%, 50 VDCW.
C623	19A116080P101	Polyester: 0.01 µf ±10%, 50 VDCW.
C624	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C625	5496287P10	Tantalum: 22 µf ±20%, 15 VDCW; sim to Sprague Type 150D.
C626	19A116080P106	Polyester: 0.058 µf ±10%, 50 VDCW.
C627	19A116080P108	Polyester: 0.15 µf ±10%, 50 VDCW.

SYMBOL	GE PART NO.	DESCRIPTION
C628*	19A116080P108	Polyester: 0.15 µf ±10%, 50 VDCW. In REV B and earlier:
	19A116080P109	Polyester: 0.22 µf ±10%, 50 VDCW.
C629	5496287P29	Tantalum: 0.68 µf ±20%, 35 VDCW; sim to Sprague Type 150D.
C630	5496287P5	Tantalum: 4.7 µf ±20%, 10 VDCW; sim to Sprague Type 150D.
C631	5496287P230	Tantalum: 0.82 µf ±20%, 35 VDCW; sim to Sprague Type 150D.
C632	5496287P18	Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague Type 150D.
C633*	19A116080P104	Polyester: 0.033 µf ±10%, 50 VDCW. Earlier than REV A:
	19A116080P105	Polyester: 0.047 µf ±10%, 50 VDCW.
C634 thru C636	5496287P226	Tantalum: 0.22 µf ±10%, 35 VDCW; sim to Sprague Type 150D.
C637	19A116080P106	Polyester: 0.068 µf ±10%, 50 VDCW.
C638	5496287P10	Tantalum: 22 µf ±20%, 15 VDCW; sim to Sprague Type 150D.
C639	7489162P25	Silver mica: 82 pf ±5%, 500 VDCW; sim to Electro Motive Type IM-15.
C640	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW.
C641 and C642	19A116080P101	Polyester: 0.01 µf ±10%, 50 VDCW.
C643	5491601P105	Phenolic: 0.22 pf ±5%, 500 VDCW.
----- DIODES AND RECTIFIERS -----		
CR601 and CR602	4038056P1	Germanium.
----- FILTERS -----		
FL601A	19B219573G3	Crystal, freq: Resonator A: 11,200000 KHZ, Resonator B: 11,190024 KHZ, Resonator A: 11,200000 KHZ, Resonator B: 11,190024 KHZ.
FL601B	19B219574G3	Crystal, freq: Resonator A: 9400.300 KHZ, Resonator B: 9396.324 KHZ, Resonator A: 9400.300 KHZ, Resonator B: 9396.324 KHZ.
FL602A		(Part of FL601A).
FL602B		(Part of FL601B).
FL603A*	19B219573G6	Crystal, freq: Resonator A: 11,200000 KHZ, Resonator B: 11,200000 KHZ. In 19D417707G1 REV D and earlier:
	19B219573G1	Crystal, freq: Resonator A: 11,200000 KHZ, Resonator B: 11,200000 KHZ.
FL603B	19B219574G1	Crystal, freq: Resonator A: 9400.300 KHZ, Resonator B: 9400.300 KHZ, Resonator A: 9400.300 KHZ, Resonator B: 9400.300 KHZ.
----- JACKS AND RECEPTACLES -----		
J601	19B219374G1	Connector. Includes: Shell.
	19C317957P1	Contact, electrical; sim to Malco X0-2854.
	19A116651P1	Contact, electrical; sim to Molex 08-54-0404.
J604 and J605	19A116779P1	Contact, electrical.
J623 and J624	19A116975P1	Contact, electrical.
----- INDUCTORS -----		
L601	7488079P18	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-9K.
L602	19B209420P125	Coil, RF: 10.0 µh ±10%, 3.10 ohms DC res max; sim to Jeffers 4446-4K.

SYMBOL	GE PART NO.	DESCRIPTION
L603A	19C31181G13	Coil.
L603B	19C31181G14	Coil.
L604	7488079P18	Choke, RF: 15.0 µh ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-9K.
----- PLUGS -----		
P904	19B219584P1	Contact, electrical: 7 pins.
----- TRANSISTORS -----		
Q601 and Q602	19A115910P1	Silicon, NPN; sim to Type 2N3904.
Q603 and Q604	19A116742P1	Silicon, NPN.
Q605	19A115910P1	Silicon, NPN; sim to Type 2N3904.
----- RESISTORS -----		
R601	3R151P153J	Composition: 15K ohms ±5%, 1/8 w.
R602	3R151P681J	Composition: 680 ohms ±5%, 1/8 w.
R603	3R152P470K	Composition: 47 ohms ±10%, 1/4 w.
R604	3R152P511J	Composition: 510 ohms ±5%, 1/4 w.
R606	3R152P102K	Composition: 1K ohms ±10%, 1/4 w.
R607	3R152P184J	Composition: 180K ohms ±5%, 1/4 w.
R608	19B209358P107	Variable, carbon film: approx 800 to 25K ohms ±10%, 0.25 w; sim to CTS Type X-201.
R609	3R152P433J	Composition: 43K ohms ±5%, 1/4 w.
R610	3R152P151J	Composition: 150 ohms ±5%, 1/4 w.
R611	3R152P822K	Composition: 8.2K ohms ±10%, 1/4 w.
R612	3R152P391J	Composition: 390 ohms ±5%, 1/4 w.
R613	3R152P472J	Composition: 4.7K ohms ±5%, 1/4 w.
R614	3R152P182J	Composition: 1.8K ohms ±5%, 1/4 w.
R615	3R152P470K	Composition: 47 ohms ±10%, 1/4 w.
R616	3R152P300K	Composition: 30 ohms ±10%, 1/4 w.
R617 and R618	19B209022P5	Wirewound: .39 ohms ±5%, 2 w; sim to IRC Type BWH.
R619	3R152P220K	Composition: 22 ohms ±10%, 1/4 w.
R620	3R152P302J	Composition: 3K ohms ±5%, 1/4 w.
R621*	3R152P472J	Composition: 4.7K ohms ±5%, 1/4 w. Deleted by REV A.
R622*	19B209358P103	Variable, carbon film: approx 50 to 1K ohms ±10%, 0.2 w; sim to CTS Type X-201. Added by REV B.
----- THERMISTORS -----		
RT601	5490828P38	Thermistor: 1.4K ohms ±5%, color code green and white; sim to Carborundum 723B-2.
----- TRANSFORMERS -----		
T601	19A116747P1	Audio freq: 500 to 4000 Hz, ±0.25 dB, Pri: 12.0 ohm ±5%, Sec 1: 8.0 ohms, 15 w, Sec 2: 1.4 ±0.10 VRMS.
----- TEST POINTS -----		
TP601	N503P304P15	Cotter pin.
----- INTEGRATED CIRCUITS -----		
U601 and U602	19A116445P1	Monolithic, linear: sim to ULN 2111.
U603*	19D416560G3	Squelch Hybrid.
	19D416560G2	In REV B and C: Squelch Hybrid.
	19D416560G1	In REV A and earlier: Squelch Hybrid.
U604	19D416573G1	Audio Hybrid.

SYMBOL	GE PART NO.	DESCRIPTION
----- NETWORKS -----		
Z601*	19B226649G4	Coil assembly. Includes:
R1	3R152P681J	Resistor, composition: 680 ohms ±5%, 1/4 w. In REV E and earlier:
	19B226649G1	Coil assembly. Includes:
R1	3R152P681J	Resistor, composition: 680 ohms ±5%, 1/4 w.
Z602*	19B226649G5	Coil assembly. Includes:
R2	3R152P512J	Resistor, composition: 5100 ohms ±5%, 1/4 w. In REV E and earlier:
	19B226649G2	Coil assembly. Includes:
R2	3R152P512J	Resistor, composition: 5.1K ohms ±5%, 1/4 w.
Z603*	19B226649G6	Coil assembly. Includes:
R3	3R152P661J	Resistor, composition: 560 ohms ±5%, 1/4 w. In REV E and earlier:
	19B226649G3	Coil assembly. Includes:
R3	3R152P661J	Resistor, composition: 560 ohms ±5%, 1/4 w.
----- MISCELLANEOUS -----		
	19B226657G1	Heat sink. (Used with Q603, Q604).
	19A134016P1	Insulator, bushing. (Used with Q603, Q604).
	4029846P1	Hex nut: No. 4-40. (Used with Q603, Q604).
	19A116023P3	Insulator, plate. (Used with Q603, Q604).
	19B226648G1	Shield. (Located by FL601, FL602).
	19B219571G1	Shield. (Located on opposite side of printed board from R601, R602).
	19B219727G1	Shield. (Located under can).
	19B219554G1	Can. (Located around U602).
	19B219555P1	Cover. (Used with can).
	19A116428P4	Contact, electrical: sim to AMP 86031-1.
	19B201109P5	Rivet.

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - To improve audio frequency response. Changed C633 and deleted R621.

REV. B - To improve operation of squelch circuit. Changed W603, added R622 and changed PWB from 19D417682 to 19D423789.

REV. C - To improve operation of squelch circuit. Changed C628.

REV. D - To improve operation of squelch circuit. Changed U603.

REV. E - 19D417707G1
To facilitate manufacturing. Changed C613A and FL603A.

REV. E - 19D417707G2
To improve operation. Changed C613B.

REV. F - 19D417707G2
To improve IF response. Changed C603B, C610B and C613B.